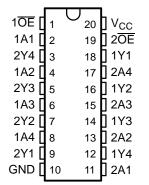
## SN74ALVCH244 OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES112F-JULY 1997-REVISED AUGUST 2004

#### **FEATURES**

- Operates From 1.65 V to 3.6 V
- Max t<sub>pd</sub> of 2.8 ns at 3.3 V
- ±24-mA Output Drive at 3.3 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

# DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



### **DESCRIPTION/ORDERING INFORMATION**

This octal buffer/line driver is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The SN74ALVCH244 is organized as two 4-bit line drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAG	iE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube	SN74ALVCH244DW	ALVCH244
-40°C to 85°C	SOIC - DW	Tape and reel	SN74ALVCH244DWR	ALVON244
	SOP - NS	Tape and reel	SN74ALVCH244NSR	ALVCH244
-40 C to 65 C	TOOOD DW	Tube	SN74ALVCH244PW	VB244
	TSSOP - PW	Tape and reel	SN74ALVCH244PWR	VB244
	TVSOP - DGV	Tape and reel	SN74ALVCH244DGVR	VB244

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

# FUNCTION TABLE (each buffer)

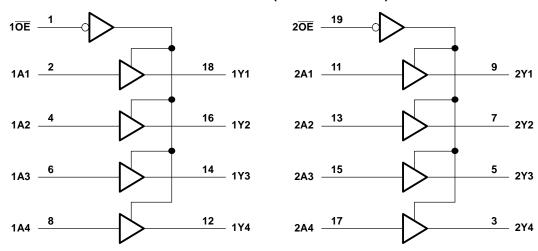
INPL	JTS	OUTPUT				
ŌĒ	Α	Y				
L	Н	Н				
L	L	L				
Н	X	Z				



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### **LOGIC DIAGRAM (POSITIVE LOGIC)**



### **ABSOLUTE MAXIMUM RATINGS**(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V	
V <sub>I</sub>	Input voltage range (2)		-0.5	4.6	V	
Vo	Output voltage range (2)(3)		-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0	-	-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0	-	-50	mA	
Io	Continuous output current		±50	mA		
	Continuous current through V <sub>CC</sub> or GN	D		±100	mA	
		DGV package	-	92		
_	Dealtoge thermal impedance (4)	DW package	-	58	°C/M	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	NS package		60	°C/W	
		PW package	83			
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



## SN74ALVCH244 OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

### **RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>**

			MIN	MAX	UNIT	
$V_{CC}$	Supply voltage		1.65	3.6	٧	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$			
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$		
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
V <sub>I</sub>	Input voltage		0	V <sub>CC</sub>	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 1.65 V		-4		
	Himb lovel output outpost	V <sub>CC</sub> = 2.3 V		-12	A	
I <sub>OH</sub>	nigri-level output current	V <sub>CC</sub> = 2.7 V		-12	mA	
	OH High-level output current	V <sub>CC</sub> = 3 V		-24		
		V <sub>CC</sub> = 1.65 V		4		
	Low lovel output ourrent	V <sub>CC</sub> = 2.3 V		12	m A	
l <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		12	mA	
		V <sub>CC</sub> = 3 V		24		
Δt/Δν	Input transition rise or fall rate	•		5	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP(1)	MAX	UNIT		
		$I_{OH} = -100  \mu A$	1.65 V to 3.6 V	V <sub>CC</sub> - 0.2				
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2				
		$I_{OH} = -6 \text{ mA}$	2.3 V	2				
V <sub>OH</sub>			2.3 V	1.7		V		
		$I_{OH} = -12 \text{ mA}$	2.7 V	2.2				
			3 V	2.4				
		I <sub>OH</sub> = -24 mA	3 V	2				
		$I_{OL} = 100 \mu A$	1.65 V to 3.6 V		0.2			
		I <sub>OL</sub> = 4 mA	1.65 V		0.45			
,		$I_{OL} = 6 \text{ mA}$	2.3 V		0.4	\ /		
VOL		1. 12 m/s	2.3 V		0.7	, V		
		I <sub>OL</sub> = 12 mA	2.7 V		0.4			
		I <sub>OL</sub> = 24 mA	3 V	1.6 V V <sub>CC</sub> - 0.2  1.2  2  1.7  2.2  2.4  2  6 V 0.2  0.45  0.4  0.7  0.4  0.55  ±5 μA  (2)  (2)  (2)  45  -45  -75  -75  ±500  ±10 μA  10 μA				
I		$V_I = V_{CC}$ or GND	3.6 V		±5	μΑ		
		V <sub>I</sub> = 0.58 V	1.65 V	(2)				
		V <sub>I</sub> = 1.07 V	1.65 V	(2)				
V <sub>OL</sub>	V <sub>I</sub> = 0.7 V	2.3 V	45					
I <sub>I(hold)</sub>		V <sub>I</sub> = 1.7 V	2.3 V	-45		μΑ		
		V <sub>I</sub> = 0.8 V	3 V	75				
		V <sub>I</sub> = 2 V	3 V	-75				
$V_{OL}$ $I_{I}$ $I_{I(hold)}$ $I_{OZ}$ $I_{CC}$ $\Delta I_{CC}$ $C_{i}$ Control inputs	$V_1 = 0 \text{ to } 3.6 \text{ V}^{(3)}$	3.6 V		±500				
l <sub>OZ</sub>		$V_O = V_{CC}$ or GND	3.6 V		±10	μΑ		
I <sub>CC</sub>		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V		10	μΑ		
		One input at V <sub>CC</sub> - 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V		750	μΑ		
	Control inputs	V V or CND	221/	4.5		"r		
C <sub>i</sub>	Data inputs	$V_{I} = V_{CC}$ or GND	3.3 V	6		þΕ		
C <sub>o</sub>	Outputs	$V_O = V_{CC}$ or GND	3.3 V	8		pF		

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = ± 0.2	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> = : ± 0.3	3.3 V 3 V	UNIT
		(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
	t <sub>pd</sub>	Α	Υ	(1)	1	3.1		3.1	1.1	2.8	ns
	t <sub>en</sub>	ŌĒ	Y	(1)	1.5	5.4		5.3	1.5	4.5	ns
	t <sub>dis</sub>	ŌĒ	Y	(1)	1	4.1		4.4	1.7	4.2	ns

<sup>(1)</sup> This information was not available at the time of publication.

All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C. This information was not available at the time of publication.

This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.







### **OPERATING CHARACTERISTICS**

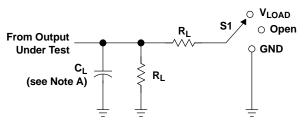
 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT	
	Power dissipation capacitance	Outputs enabled	C <sub>1</sub> = 0. f = 10 MHz	(1)	22	28	pF
Cpd	per buffer/driver	Outputs disabled	$C_L = 0$ , $I = 10$ MHZ	(1)	1.5	4	ρг

<sup>(1)</sup> This information was not available at the time of publication.



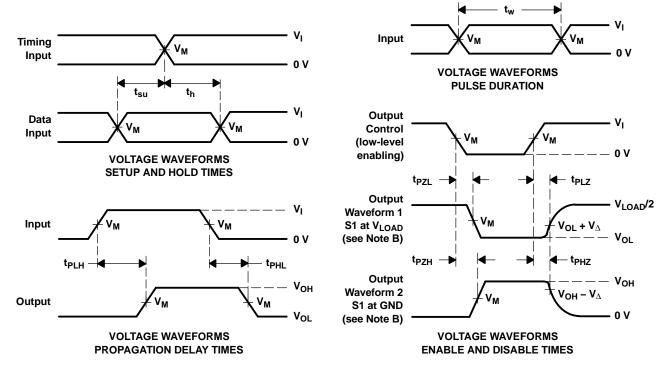
### PARAMETER MEASUREMENT INFORMATION



TEST	<b>S</b> 1
t <sub>pd</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LOAD CIRCUIT

V	IN	PUT	V	V		В	V	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	$R_L$	$V_{\!\scriptscriptstyle \Delta}$	
1.8 V $\pm$ 0.15 V	V <sub>CC</sub>	≤ <b>2</b> ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V	
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤ <b>2</b> ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>500</b> Ω	0.15 V	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V	
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V	



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{\Omega}$  = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74ALVCH244DGVR	Active	Production	TVSOP (DGV)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244
SN74ALVCH244DGVR.B	Active	Production	TVSOP (DGV)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244
SN74ALVCH244DW	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH244
SN74ALVCH244DW.B	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH244
SN74ALVCH244DWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH244
SN74ALVCH244DWR.B	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH244
SN74ALVCH244PW	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244
SN74ALVCH244PW.B	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244
SN74ALVCH244PWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244
SN74ALVCH244PWR.B	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244
SN74ALVCH244PWRE4	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB244

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



### PACKAGE OPTION ADDENDUM

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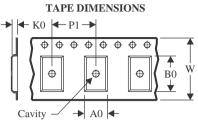
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# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH244DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74ALVCH244DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ALVCH244PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

**PACKAGE MATERIALS INFORMATION** 

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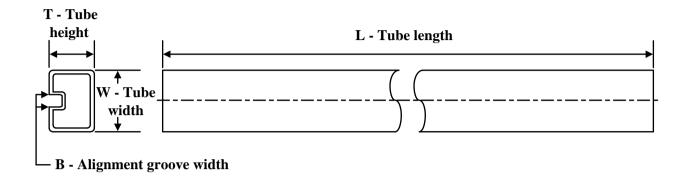
### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH244DGVR	TVSOP	DGV	20	2000	353.0	353.0	32.0
SN74ALVCH244DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74ALVCH244PWR	TSSOP	PW	20	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 24-Jul-2025

### **TUBE**

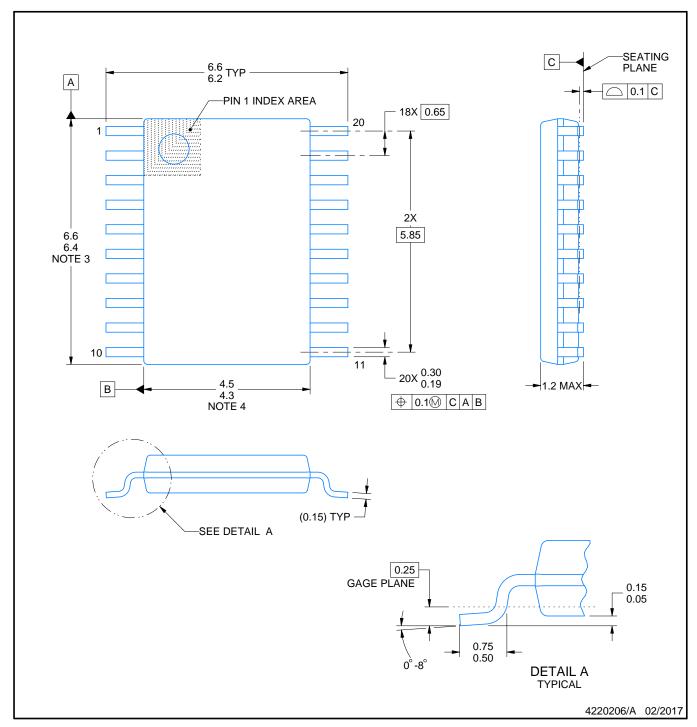


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74ALVCH244DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74ALVCH244DW.B	DW	SOIC	20	25	507	12.83	5080	6.6
SN74ALVCH244PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74ALVCH244PW.B	PW	TSSOP	20	70	530	10.2	3600	3.5



SMALL OUTLINE PACKAGE



#### NOTES:

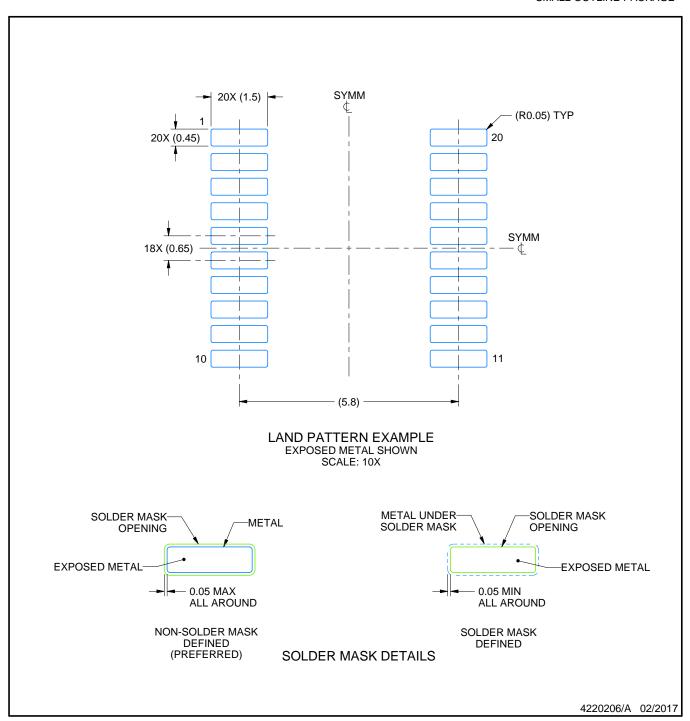
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



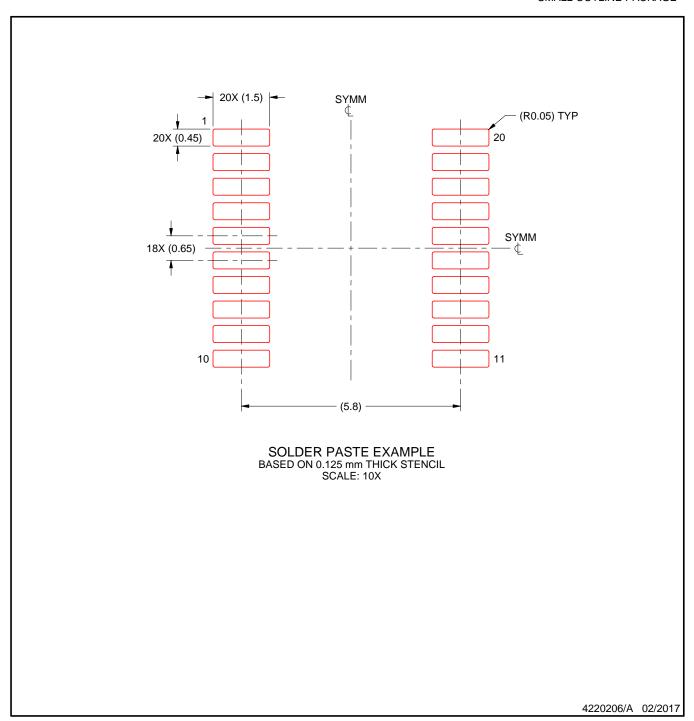
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### DGV (R-PDSO-G\*\*)

### 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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